Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-293-8401

# Inclosure Material:

Plastic

# Overall Length:

Between 0.140 inches and 0.195 inches

# **Terminal Length:**

Between 0.900 inches and 1.300 inches

# **Overall Diameter:**

Between 0.135 inches and 0.185 inches

### **Function For Which Designed:**

Transient suppressor

#### Mounting Method:

Terminal

### **Features Provided:**

Hermetically sealed case and quality assurance level tx

### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

130.0 breakdown voltage, dc and 98.8 working peak reverse voltage

# Voltage Tolerance In Percent:

-5.0/+5.0

# **Current Rating Per Characteristic:**

5.00 microamperes forward current, average peak

# **Power Rating Per Characteristic:**

3.0 watts small-signal input power, common-collector major

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/516 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

--

## Demilitarization:

No

Fiig:

A110a0